MINI-MELF-SMD

Applications



Silicon Switching Diode

1N914UR-1 / LL914

Used in general purpose applications, where performance, space and switching speed are important. LL-34/35 MINI MELF

Features

- Six sigma quality
- Metallurgically bonded
- BKC's Sigma Bond[™] plating for problem free solderability
- Also comes in DO-35 glass package
- Full UR approval to Mil-S-19500/116
- Available up to JANTXV levels
 - "S" level screening available to Source Control Drawings

Maximum Ratings	Symbol	Value	Unit
Peak Inverse Voltage	PIV	100 (Min.)	Volts
Average Rectified Current	I _{Avg}	200	mAmps
Continuous Forward Current	I _{Fdc}	300	mAmps
Peak Surge Current (t _{peak} = 1 sec.)	l _{peak}	1.0	Amp
BKC Power Dissipation @ end cap T = 50 $^{\circ}$ C	P _{tot}	500	mWatts
Storage & Operating Temperature Range	T _{St & Op}	-65 to +200	° C

Electrical Characteristics @ 25 °C	Symbol	Maximum Limits	Unit
Forward Voltage Drop @ I _F = 10 mA	V _F	1.0	Volts
Forward Voltage Drop @ I _F = 100 mA	V _F	1.2	Volts
Reverse Leakage Current @ V _R = 20 V	l _R	0.025 (50 @ 150 °C)	μA
Reverse Leakage Current @ V_{R} = 75 V	I _R	0.50 (100 @ 150 °C)	μA
Capacitance @ $V_R = 0 V$, f = 1mHz	C _T	4.0	pF
Capacitance @ V _R = 1.5 V , f = 1mHz	C _T	2.8	pF
Reverse Recovery Time (note 1)	t _{rr}	5.0	nSecs
Forward Recovery Time (note 2)	V_{fr}	20	nSecs

Note 1: $I_F = I_R = 10 \text{ mA}, R_L = 100 \text{ Ohms}$ Note 2: $I_F = 50 \text{ mA dc}$

To order MIL parts, use the 1N914UR-1 number with the appropriate JAN, JTX or JTXV prefix.

1N914-1 DO-35 glass leaded parts also available in both commercial and military versions.



